

## INTEGRATED 1 WATT AUDIO AMPLIFIER

A complete a. f. amplifier in monolithic integrated form incorporating special measures to prevent cross-over distortion throughout an exceptionally wide usable range of supply voltage (4.5 V to 10 V). This, in combination with its low drain current, makes the TAA300 ideally suited for use in battery operated equipment. Due to the high a. c. feedback ( $\approx 20$  dB) the distortion and spread in gain is very low.

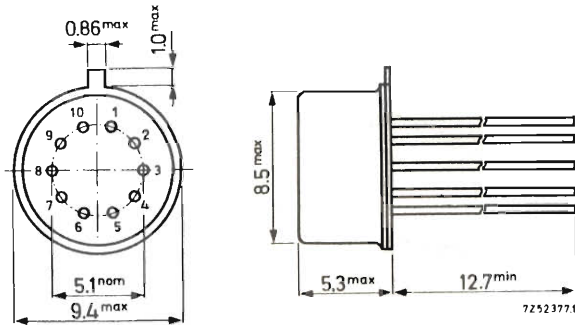
### QUICK REFERENCE DATA

Supply voltage	$V_B$	nom.	9 V
Output power	$P_O$	typ.	1 W
Input signal for $P_O = 1$ W	$V_i$	typ.	8.5 mV
Input impedance	$ Z_i $	typ.	15 k $\Omega$
Load impedance	$R_L$		8 $\Omega$
Total current (no signal)	$I_{tot}$	typ.	8 mA

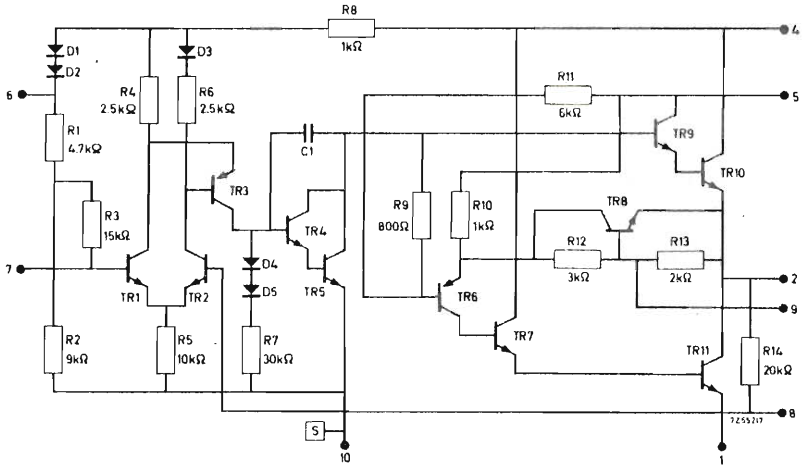
### PACKAGE OUTLINE

Dimensions in mm

XA10 (TO-74; reduced height)



## CIRCUIT DIAGRAM



**RATINGS** Limiting values in accordance with the Absolute Maximum System (IEC134)

Voltages (see test set-up on page 4)

$V_{4-1}$	max.	10.5 V
$V_{7-8}$	max.	6 V
$V_{8-7}$	max.	6 V
$V_{2-9}$	max.	6 V
$V_{2-1}$	max.	10.5 V
$V_{4-2}$	max.	10.5 V

Currents (see test set-up on page 4)

$-I_1$	max.	600 mA
$\pm I_2$	max.	600 mA
$+I_4$	max.	600 mA

Total power dissipation

$P_{tot}$  see next page

Temperatures

Storage temperature

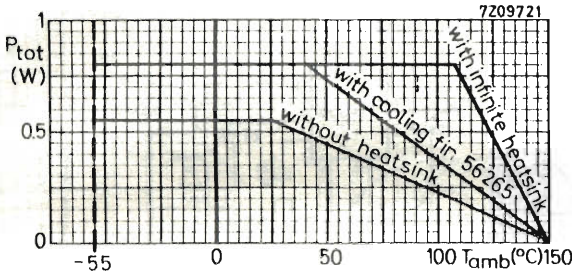
$T_{stg}$  -55 to +150 °C

Operating ambient temperature

$T_{amb}$  -55 to +150 °C

**RATINGS** (continued)

Maximum allowable total power dissipation versus ambient temperature

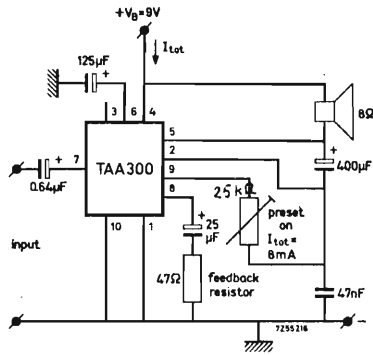


**CHARACTERISTICS** at T<sub>amb</sub> = 25 °C; V<sub>B</sub> = 9 V

Measured in the test set-up on page 4

<u>Output power</u> at d <sub>tot</sub> = 10%	P <sub>O</sub>	typ.	1 W
<u>Bandwidth</u> (-3 dB)	B	>	10 kHz
		typ.	25 kHz
<u>Total current</u> (d.c.) no signal and excluding output transistors: with signal at P <sub>O</sub> = 1 W:	I <sub>tot</sub>	typ.	4 mA
	I <sub>tot</sub>	typ.	180 mA
<u>Total distortion</u> at P <sub>O</sub> = 0.5 W	d <sub>tot</sub>	typ.	0.7 %
		<	3 %
<u>Input signal</u> at P <sub>O</sub> = 1 W P <sub>O</sub> = 0.5 W	V <sub>i</sub>	typ.	8.5 mV
	V <sub>i</sub>	<	8.5 mV
<u>Input impedance</u>	Z <sub>i</sub>	>	10 kΩ
		typ.	15 kΩ
<u>Efficiency</u>	η	typ.	60 %
<u>Signal to noise ratio</u> related to P <sub>O</sub> = 1 W R <sub>S</sub> = 2 kΩ; B = 30 Hz to 15 kHz	S/N	>	70 dB
		typ.	75 dB
<u>Noise output power</u> input short circuited; B = 30 Hz to 15 kHz	P <sub>N</sub>	typ.	10 nW
		<	20 nW
<u>Preset resistor</u> for I <sub>tot</sub> = 8 mA	R <sub>pr</sub>		4 to 25 kΩ

## TEST SET-UP



To prevent high-frequency instability, the following precautions must be taken.

- Keep the lead inductance from the positive voltage supply to pin 4 to a minimum.
- Because of the high internal resistance of batteries (especially at end of life) a large capacitance should be connected between pin 4 and ground.
- A capacitor of at least 47 nF should be connected between pin 2 and ground to prevent instability of the lower Darlington output transistor (see also test set-up).
- Avoid coupling between output and input leads (especially those carrying signals from a high-impedance source). This coupling can be reduced by using short leads, shielded input cable or by limiting the upper frequency to 15 kHz by means of a capacitor of 560 pF between pin 7 and ground.

